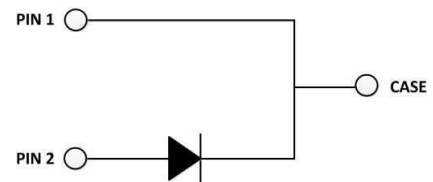


3rd Generation 650V/20A SiC Schottky Barrier Diode

Features

- AEC-Q101 qualified
- Revolutionary semiconductor material - Silicon Carbide (SiC)
- No reverse recovery
- High-speed switching performance
- Temperature-independent switching behavior
- System cost / size savings due to reduced cooling requirements
- Junction temperature range from -55°C to 175°C
- RoHS compliant



Package Type: TO-252-2L

Potential Applications

- DC/DC converter for EV/HEV
- On board charger (OBC)



Description

The ADS065J020D3 SiC Schottky Barrier Diode (SBD) has been developed using Sanan’s advanced 3rd generation SiC SBD technology with the highest performance and reliability. It registers higher efficiency, higher operation temperature and lower loss and can be operated at higher frequency than Si-based solutions. As to the Schottky structure, it shows no recovery at turn-off and allows a low leakage current with reverse voltage up to 650V. It can contribute to system miniaturization and achieve lightweight system design. Using RoHS compliant components and being AEC-Q101 qualified, it is qualified for use in automotive application.

Product Specifications

Device	V _{RRM}	I _F (135°C)	V _F (25°C)	Q _C	Marking
ADS065J020D3	650V	25A	1.35V	55nC	DS065020D3

Electrical Characteristic Diagrams

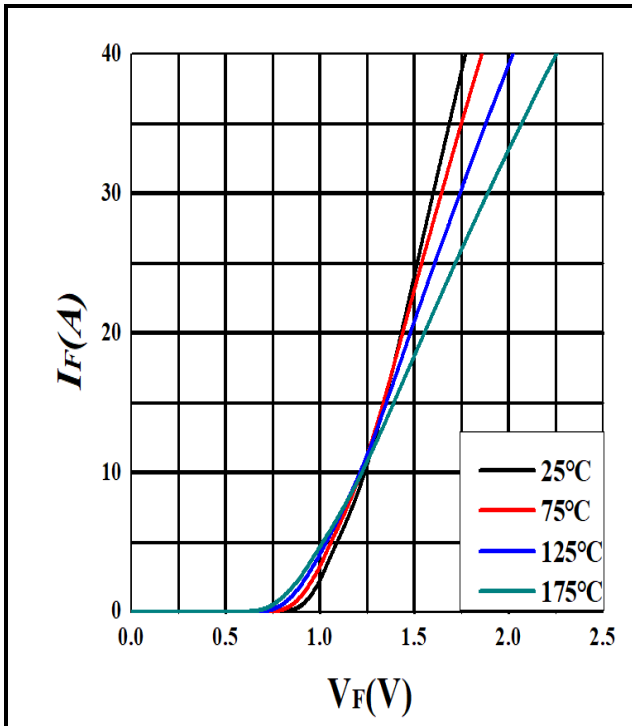


Figure 1. Forward characteristics

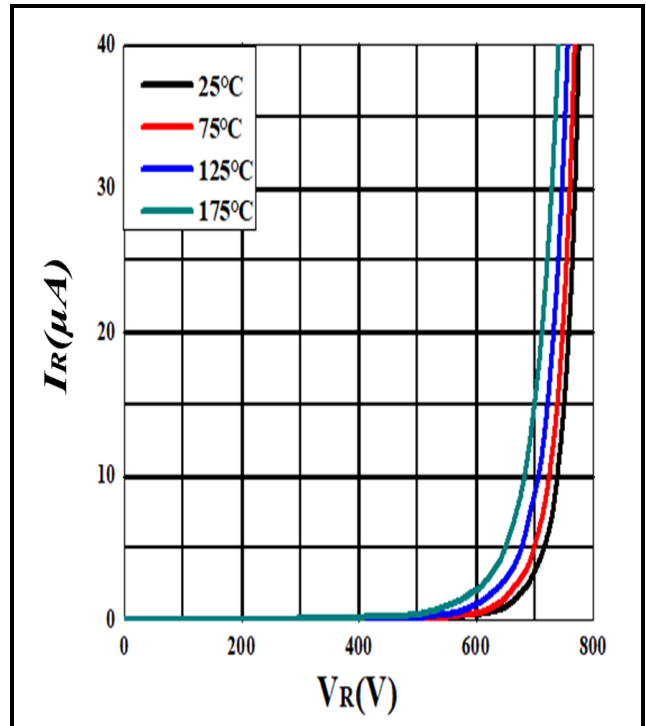


Figure 2. Reverse characteristics

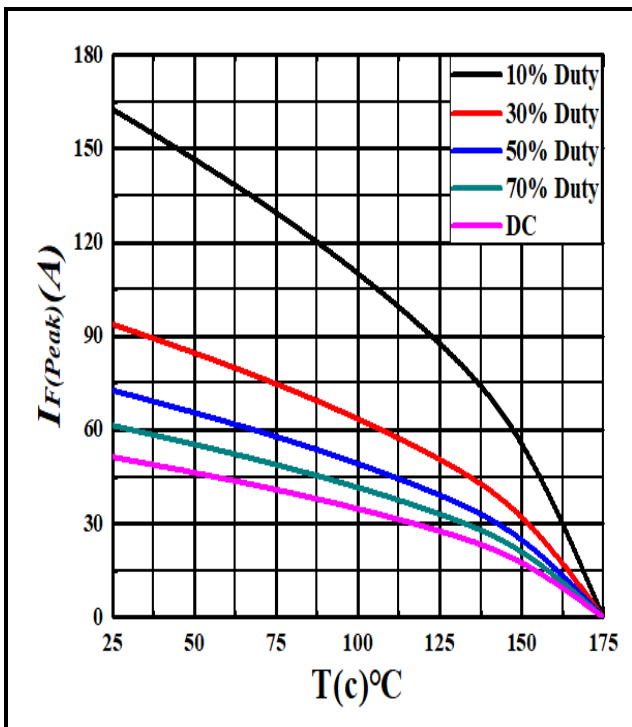


Figure 3. Current derating

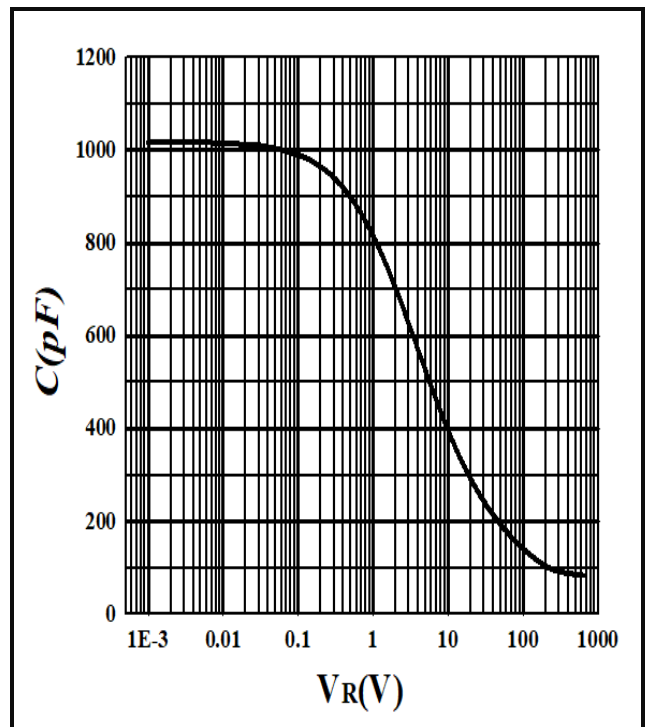


Figure 4. Capacitance vs. reverse voltage

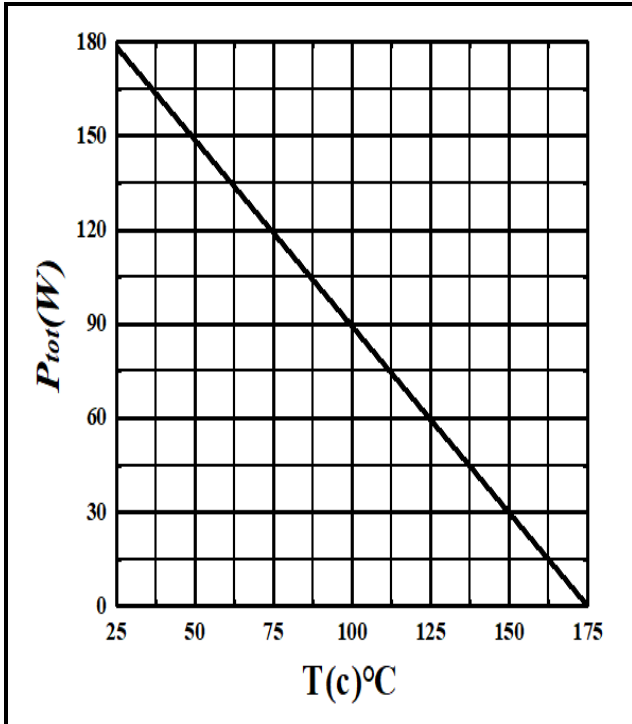


Figure 5. Power derating

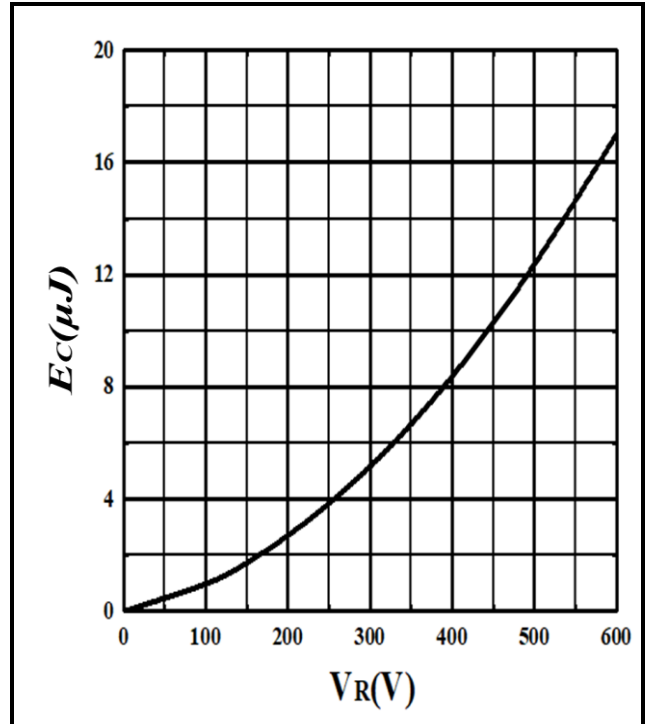


Figure 6. Capacitance stored energy

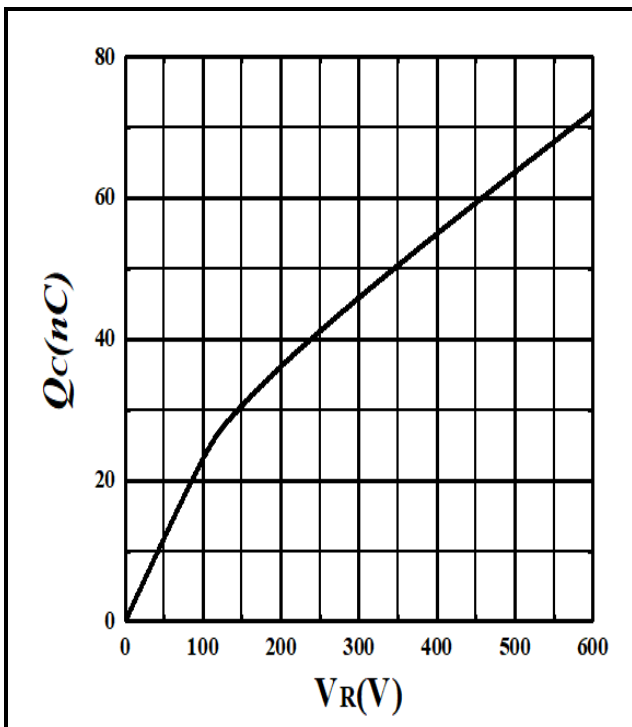
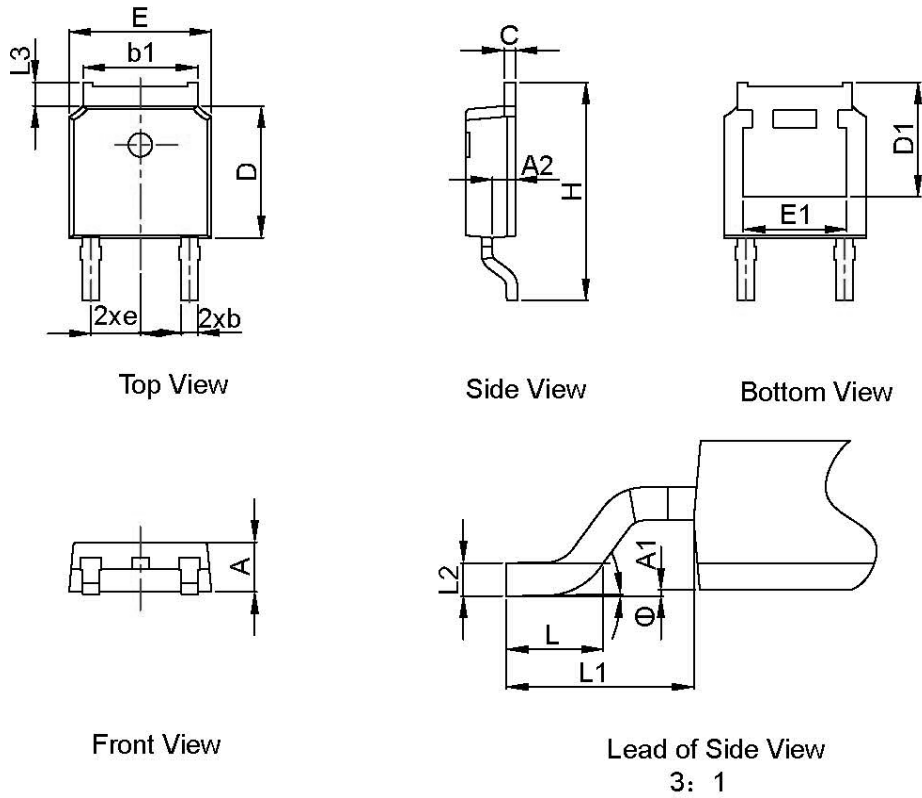


Figure 7. Total capacitance charge vs. reverse voltage

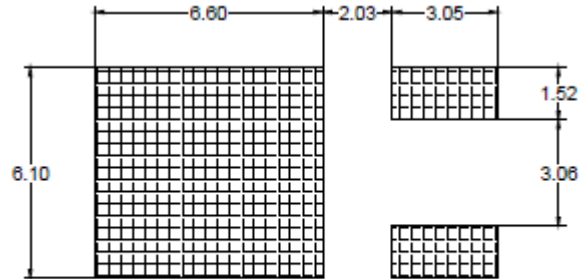
Package Information



Dimension unit: [mm]			
Symbol	Min	Nom	Max
A	2.20	2.30	2.38
A1	0	-	0.127
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b1	5.20	5.33	5.46
c	0.43	0.53	0.61
D	5.98	6.10	6.22
D1	5.30 REF		
E	6.40	6.60	6.73
E1	4.63	-	-
e	2.286 BSC		
H	9.40	10.10	10.50
L	1.38	1.50	1.75
L1	2.743 REF		
L2	0.51 BSC		
L3	0.88	-	1.28
θ	0°	-	8°

Recommended Solder Pad Layout

Note: All dimensions are in mm



TO-252-2L

Ordering Information

Part number	ADS065J020D3-ASATH
Package	TO-252-2L
Unit quantity	2500 EA
Packing type	Tape & Reel

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